DISCRETE SEMICONDUCTORS

DATA SHEET

BFR106NPN 5 GHz wideband transistor

Product specification

September 1995



NPN 5 GHz wideband transistor

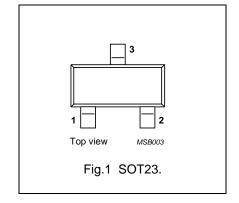
BFR106

DESCRIPTION

NPN silicon planar epitaxial transistor in a plastic SOT23 envelope. It is primarily intended for low noise, general RF applications.

PINNING

PIN	DESCRIPTION		
	Code: R7p		
1	base		
2	emitter		
3	collector		



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	_	20	V
V _{CEO}	collector-emitter voltage	open base	_	_	15	V
I _C	DC collector current		_	_	100	mA
P _{tot}	total power dissipation	up to T _s = 70 °C; note 1	_	-	500	mW
h _{FE}	DC current gain	$I_C = 50 \text{ mA}; V_{CE} = 9 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$	25	80	_	
f _T	transition frequency	$I_C = 50 \text{ mA}; V_{CE} = 9 \text{ V}; f = 500 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$	_	5	_	GHz
G _{UM}	maximum unilateral power gain	$I_C = 30 \text{ mA}; V_{CE} = 6 \text{ V}; f = 800 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$	_	11.5	_	dB
Vo	output voltage	I_C = 50 mA; V_{CE} = 9 V; R_L = 75 Ω; T_{amb} = 25 °C; d_{im} = -60 dB; $f_{(p+q-r)}$ = 793.25 MHz	_	350	_	mV

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	20	V
V_{CEO}	collector-emitter voltage	open base	-	15	V
V _{EBO}	emitter-base voltage	open collector	_	3	V
Ic	DC collector current		_	100	mA
P _{tot}	total power dissipation	up to T _s = 70 °C; note 1	_	500	mW
T _{stg}	storage temperature		-65	150	°C
Tj	junction temperature		_	175	°C

Note

1. T_s is the temperature at the soldering point of the collector tab.

NPN 5 GHz wideband transistor

BFR106

THERMAL RESISTANCE

SYMBOL	PARAMETER	CONDITIONS	THERMAL RESISTANCE
R _{th j-s}	thermal resistance from junction to soldering point	up to $T_s = 70$ °C; note 1	210 K/W

Note

1. $T_{\mbox{\scriptsize S}}$ is the temperature at the soldering point of the collector tab.

CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 10 V	_	_	100	nA
h _{FE}	DC current gain	$I_C = 50 \text{ mA}; V_{CE} = 9 \text{ V}$	25	80	_	
f _T	transition frequency	I_C = 50 mA; V_{CE} = 9 V; f = 500 MHz; T_{amb} = 25 °C	_	5	_	GHz
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = 10 \text{ V}$; $f = 1 \text{ MHz}$	_	1.5	_	pF
C _e	emitter capacitance	$I_C = I_c = 0$; $V_{EB} = 0.5 \text{ V}$; $f = 1 \text{ MHz}$	_	4.5	_	pF
C _{re}	feedback capacitance	I _C = 0; V _{CE} = 10 V; f = 1 MHz	-	1.2	-	pF
G _{UM}	maximum unilateral power gain (note 1)	$I_C = 30 \text{ mA}; V_{CE} = 6 \text{ V}; f = 800 \text{ MHz}; $ $T_{amb} = 25 ^{\circ}\text{C}$	_	11.5	_	dB
F	noise figure	$I_C = 30 \text{ mA}; V_{CE} = 6 \text{ V}; f = 800 \text{ MHz}; $ $T_{amb} = 25 ^{\circ}\text{C}$	_	3.5	_	dB
d ₂	second order intermodulation distortion	note 2	_	-50	_	dB
Vo	output voltage	note 3	_	350	_	mV

Notes

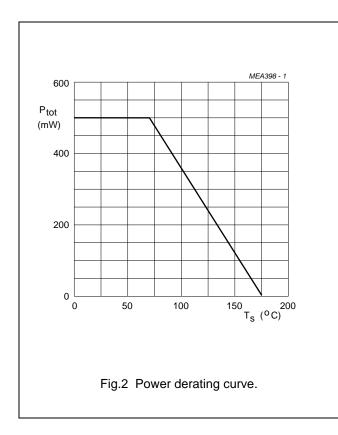
1. $\,\,G_{UM}$ is the maximum unilateral power gain, assuming S_{12} is zero and

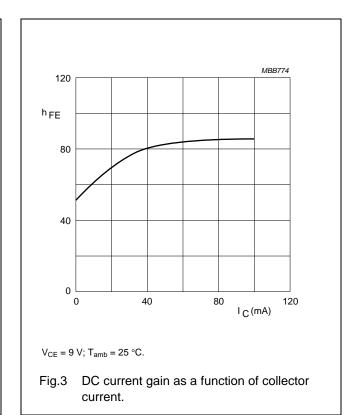
$$G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} dB.$$

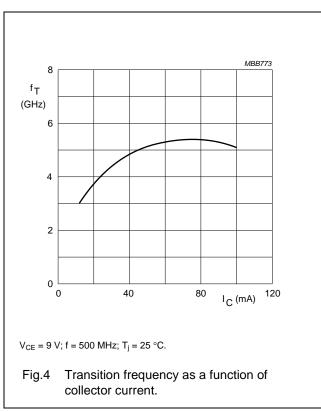
- 2. $I_C = 30$ mA; $V_{CE} = 6$ V; $R_L = 75$ Ω ; $T_{amb} = 25$ °C; $f_{(p+q)} = 810$ MHz; $V_o = 100$ mV.
- 3. $d_{im} = -60 \text{ dB (DIN } 45004 \text{B)}; \ I_C = 50 \text{ mA}; \ V_{CE} = 9 \text{ V}; \ R_L = 75 \ \Omega; \ T_{amb} = 25 \ ^{\circ}C; \ f_{(p+q-r)} = 793.25 \ \text{MHz}.$

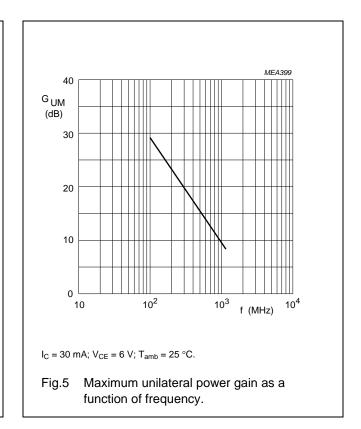
NPN 5 GHz wideband transistor

BFR106



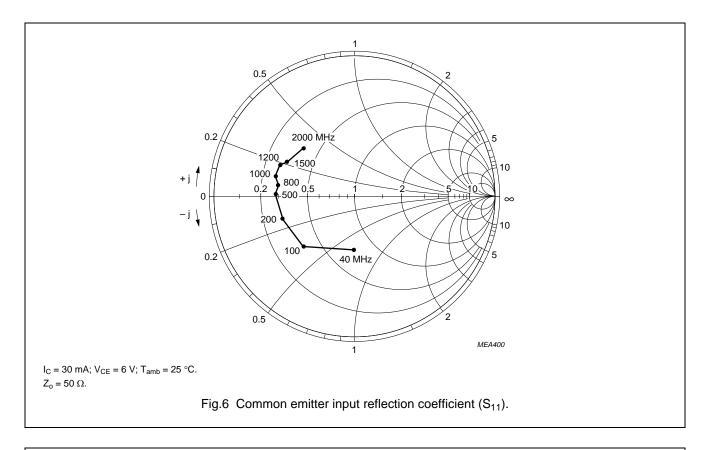


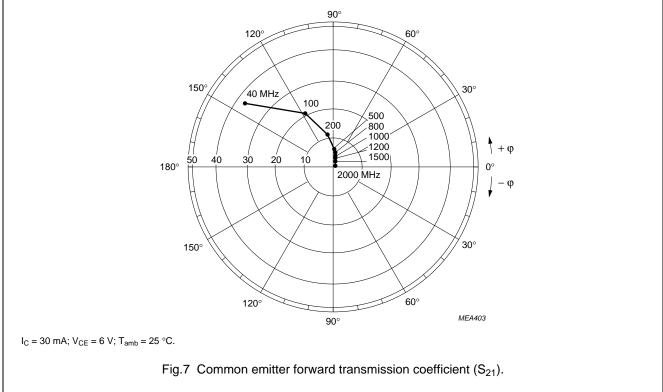




NPN 5 GHz wideband transistor

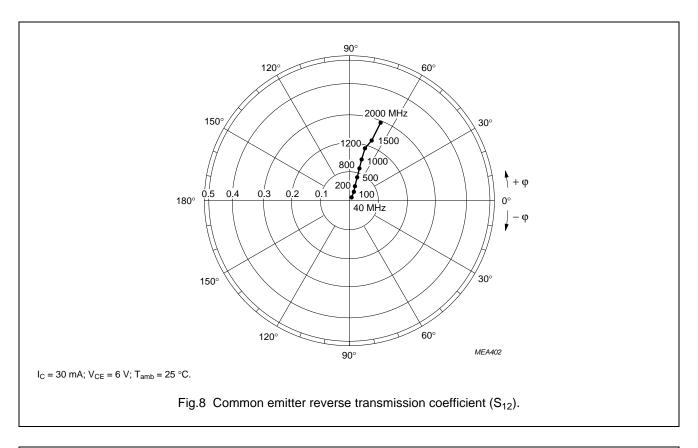
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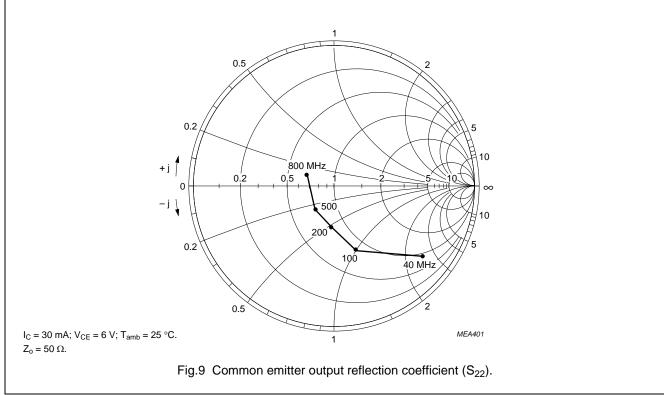




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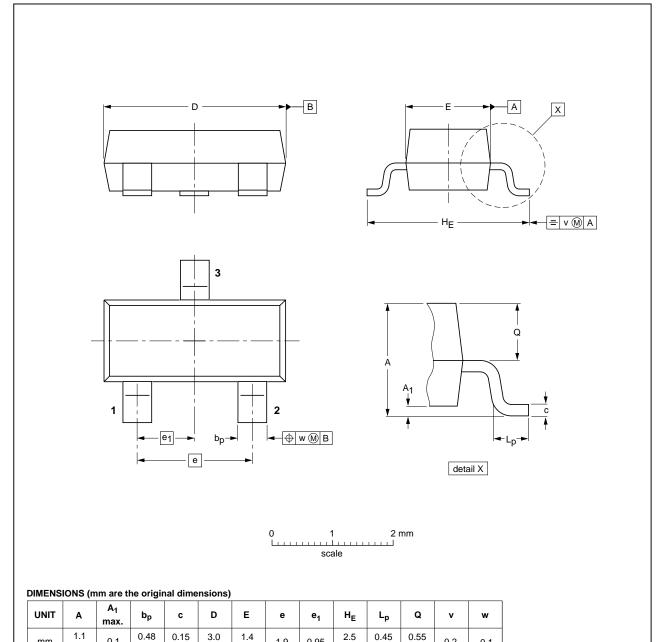
NPN 5 GHz wideband transistor

BFR106

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB				-04-11-04 06-03-16

0.95

1.9

0.1

0.2

mm

0.1

0.9

0.38

NPN 5 GHz wideband transistor

BFR106

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NPN 5 GHz wideband transistor

BFR106

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